NSN 5961-00-256-8803

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View Online at https://aerobasegroup.com/nsn/5961-00-256-8803 **Inclosure Material:** Metal **Overall Length:** 1.003 inches **Overall Height:** 0.330 inches Overall Width: 0.505 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 breakdown voltage, collector-to-base, emitter open and 300.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 3.00 microamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 00752-334761 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead and 1 case Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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